

SIHG33N65E-GE3 Information


For Reference Only

Part Number [SIHG33N65E-GE3](#)
Manufacturer Vishay Siliconix
Category Discrete Semiconductor Products
[Transistors - FETs, MOSFETs - Single](#)
Description MOSFET N-CH 650V 32.4A TO-247AC
Package TO-247-3
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com


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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


SIHG33N65E-GE3 Specifications

Manufacturer Part Number	SIHG33N65E-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Package	TO-247-3
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	32.4A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	173nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4040pF @ 100V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	313W (Tc)
Rds On (Max) @ Id, Vgs	105 mOhm @ 16.5A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247AC
Package / Case	TO-247-3

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SIHG33N65E-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

SIHG33N65E-GE3 Payment Methods



SIHG33N65E-GE3 Shipping Methods



If you have any question about SIHG33N65E-GE3, please do not hesitate to contact us!

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